

Features

- $BV_{CEO} > -30V$
- $BV_{EBO} > -8V$
- Continuous Current I_C to -7.5A
- Peak Pulse Current I_{CM} to -14A
- Ultra-Low Saturation Voltage $V_{CE(sat)} < -35mV$ @ -1A
- High Current $R_{CE(sat)} = 13m\Omega$ Typical
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Wettable Flank for Improved Optical Inspection
- Rated to +175°C – Ideal for High-Temperature Environments
- Complementary NPN Type: [DXTN80030DFGQ](#)
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The DXTP80030DFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

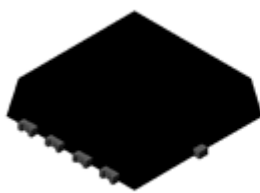
Mechanical Data

- Package: PowerDI®3333-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin. Solderable per MIL-STD-202, Method 208 ③
- Weight: 0.03 grams (Approximate)

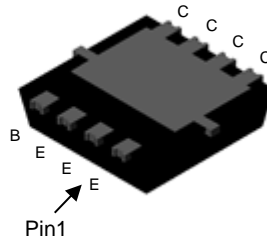
Applications

- MOSFET & IGBT gate drivers
- Power lines or load switches
- Low drop voltage regulations
- DC to DC converters
- Motors, solenoids, relays and actuator drivers

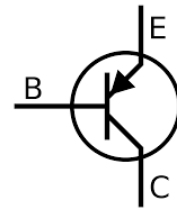
PowerDI3333-8/SWP (Type UX)



Top View



Bottom View



Device Symbol

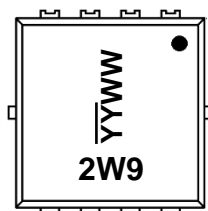
Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
DXTP80030DFGQ-7	PowerDI3333-8/SWP (Type UX)	2W9	7	12	2,000	Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information

PowerDI3333-8/SWP (Type UX)



2W9 = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 25 = 2025)
WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated in the United States and other countries.

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-30	V
Emitter-Base Voltage	V _{EBO}	-8	V
Continuous Collector Current (Note 5)	I _C	-4	A
Continuous Collector Current (Note 7)	I _C	-7.5	A
Peak Pulse Current	I _{CM}	-14	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

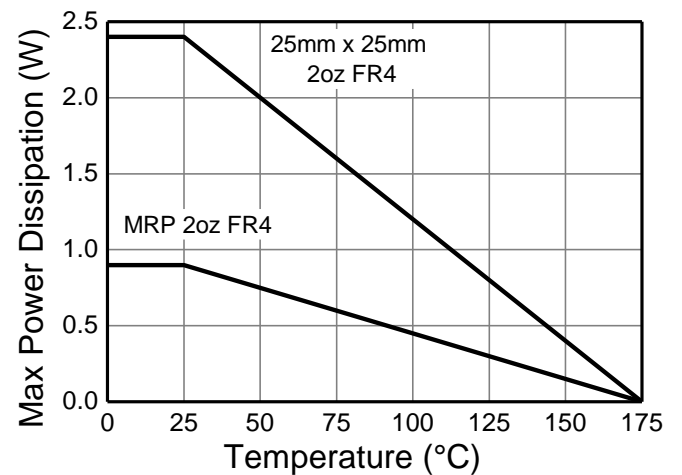
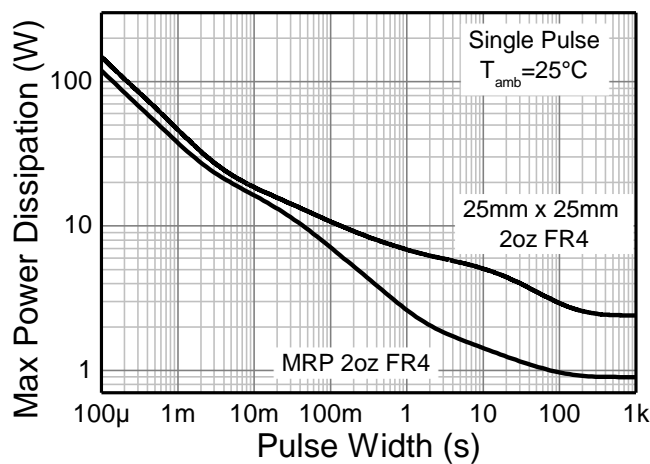
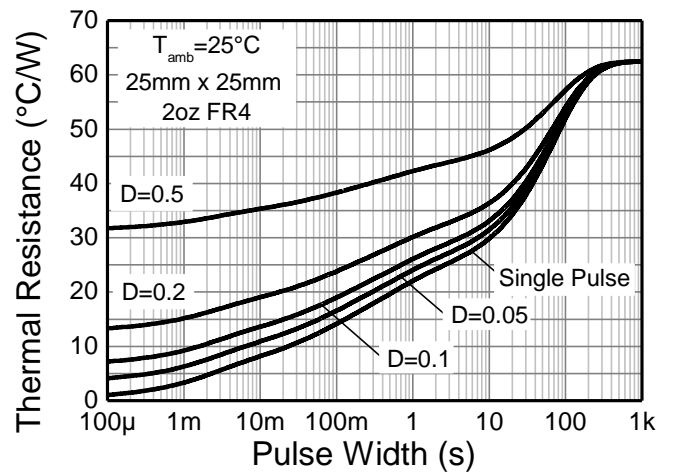
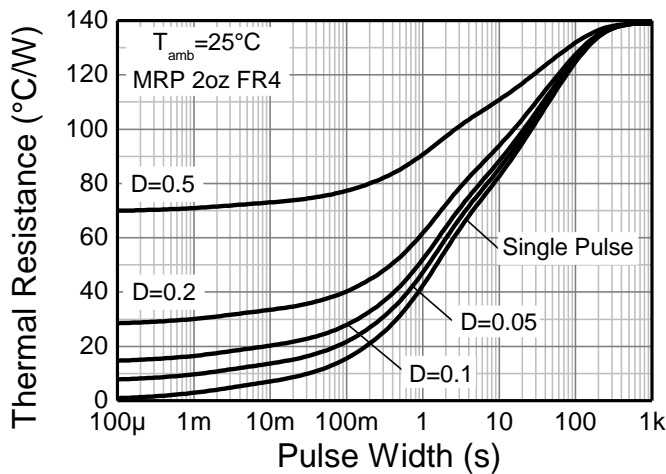
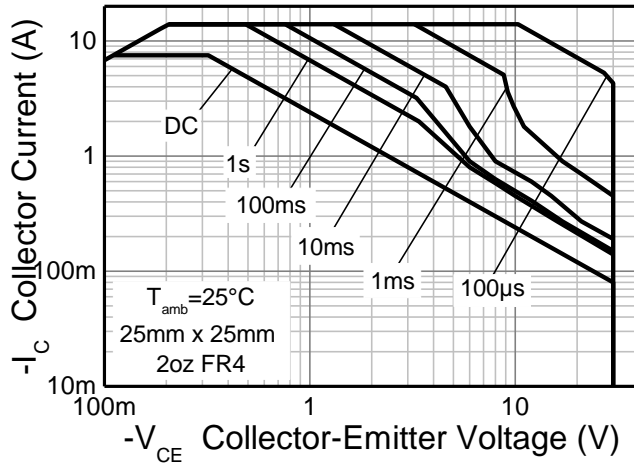
Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	900	mW
		1.6	W
		2.4	W
Thermal Resistance, Junction to Ambient	R _{θJA}	140	°C/W
		92	°C/W
		62.5	°C/W
Thermal Resistance, Junction to Case (Note 7)	R _{θJC}	6.5	°C/W
Thermal Resistance, Junction to Lead (Note 8)	R _{θJL}	4.2	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +175	°C

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C
Electrostatic Discharge - Charged Device Model	ESD CDM	1,000	V	IV

- Notes:
5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady state.
 6. Same as Note 5, except the device is mounted on 15mm x 15mm 2oz copper.
 7. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
 8. Thermal resistance from junction to solder-point (at the collector tab).
 9. Refer to JEDEC specifications JESD22-A114, JESD22-A115 and JESD22-C101.

Thermal Characteristics and Derating Information



Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	-40	—	—	V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage (Note 10)	BV_{CEO}	-30	—	—	V	$I_C = -10\text{mA}$
Emitter-Collector Breakdown Voltage	BV_{ECO}	-5	—	—	V	$I_E = -100\mu\text{A}$
Emitter-Base Breakdown Voltage	BV_{EBO}	-8	—	—	V	$I_E = -100\mu\text{A}$
Collector Cutoff Current	I_{CBO}	—	—	-100	nA	$V_{CB} = -30\text{V}$
		—	—	-10	μA	$V_{CB} = -30\text{V}$, $T_A = +125^\circ\text{C}$
Collector Cutoff Current	I_{CES}	—	—	-300	nA	$V_{CE} = -24\text{V}$
Emitter Cutoff Current	I_{EBO}	—	—	-50	nA	$V_{EB} = -7\text{V}$
Collector-Emitter Saturation Voltage (Note 10)	$V_{CE(sat)}$	—	-35	—	mV	$I_C = -100\text{mA}$, $I_B = -1\text{mA}$
		—	-40	-65	mV	$I_C = -1\text{A}$, $I_B = -20\text{mA}$
		—	-22	-35	mV	$I_C = -1\text{A}$, $I_B = -100\text{mA}$
		—	-115	-150	mV	$I_C = -4\text{A}$, $I_B = -80\text{mA}$
		—	-130	-220	mV	$I_C = -7.5\text{A}$, $I_B = -375\text{mA}$
Base-Emitter Saturation Voltage (Note 10)	$V_{BE(sat)}$	—	-825	-950	mV	$I_C = -4\text{A}$, $I_B = -80\text{mA}$
		—	-940	-1,100	mV	$I_C = -7.5\text{A}$, $I_B = -375\text{mA}$
Base-Emitter Turn-On Voltage (Note 10)	$V_{BE(on)}$	—	-760	-900	mV	$I_C = -4\text{A}$, $V_{CE} = -2\text{V}$
		—	-795	-900	mV	$I_C = -7.5\text{A}$, $V_{CE} = -2\text{V}$
DC Current Gain (Note 10)	h_{FE}	250	440	—	—	$I_C = -10\text{mA}$, $V_{CE} = -2\text{V}$
		300	430	550	—	$I_C = -100\text{mA}$, $V_{CE} = -2\text{V}$
		240	375	—	—	$I_C = -1\text{A}$, $V_{CE} = -2\text{V}$
		220	335	—	—	$I_C = -2\text{A}$, $V_{CE} = -2\text{V}$
		180	280	—	—	$I_C = -4\text{A}$, $V_{CE} = -2\text{V}$
		120	200	—	—	$I_C = -7.5\text{A}$, $V_{CE} = -2\text{V}$
Input Capacitance	C_{ibo}	—	530	—	pF	$V_{EB} = 0.5\text{V}$, $f = 1\text{MHz}$
Output Capacitance	C_{obo}	—	50	—	pF	$V_{CB} = 10\text{V}$, $f = 1\text{MHz}$
Current Gain-Bandwidth Product	f_T	100	190	—	MHz	$V_{CE} = -10\text{V}$, $I_C = -100\text{mA}$ $f = 50\text{MHz}$
Turn-On Time	t_d	—	13.5	—	ns	$V_{CC} = -10\text{V}$, $I_C = -4\text{A}$ $I_{B1} = -I_{B2} = -400\text{mA}$
	t_r	—	40	—	ns	
Turn-Off Time	t_s	—	140	—	ns	
	t_f	—	6.5	—	ns	

Note: 10. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

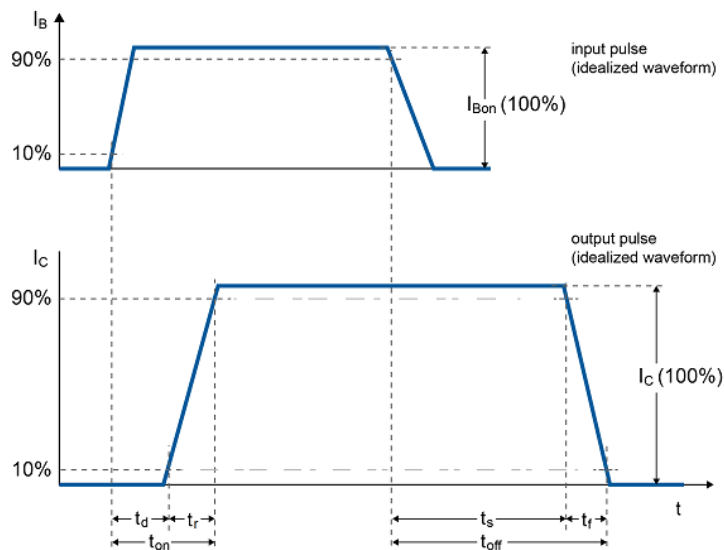


Fig. 6 Timing Waveform

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

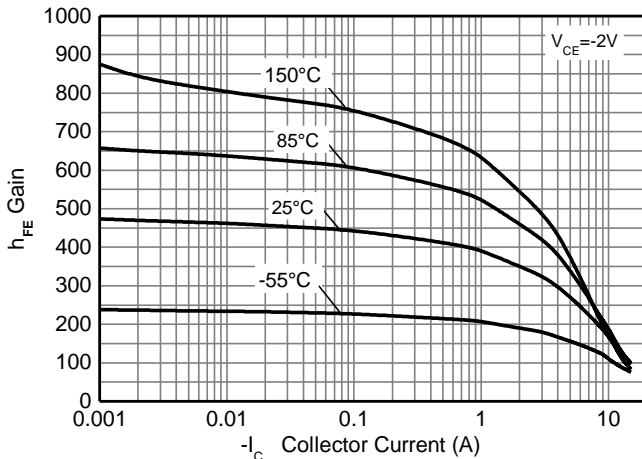


Fig. 7 $h_{FE} \text{ v } I_C$

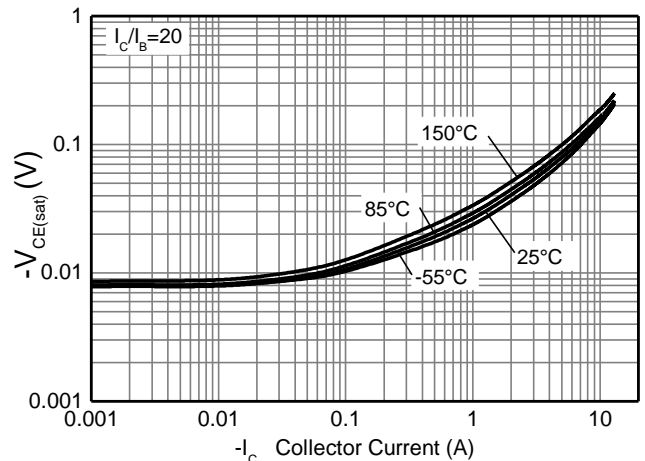


Fig. 8 $V_{CE(sat)} \text{ v } I_C$

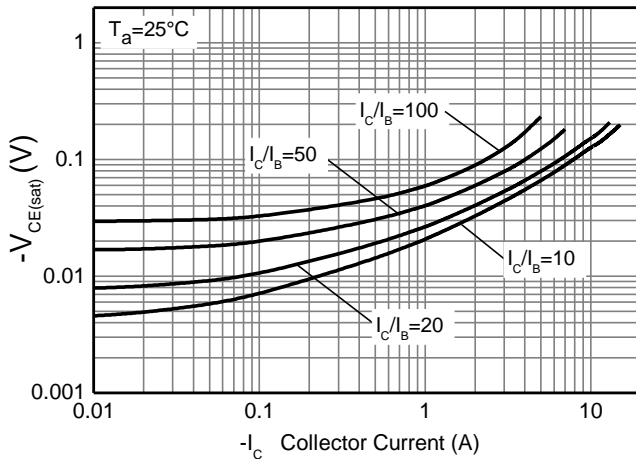


Fig. 9 $V_{CE(sat)} \text{ v } I_C$

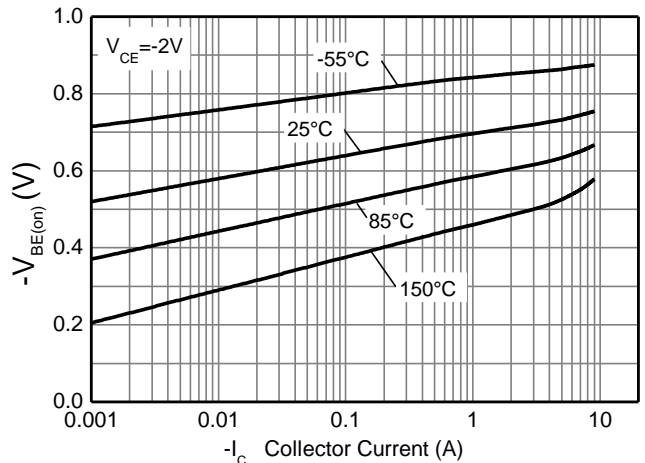


Fig. 10 $V_{BE(on)} \text{ v } I_C$

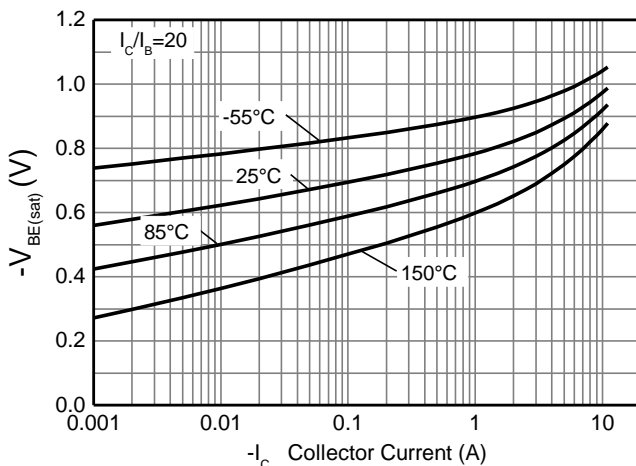


Fig. 11 $V_{BE(sat)} \text{ v } I_C$

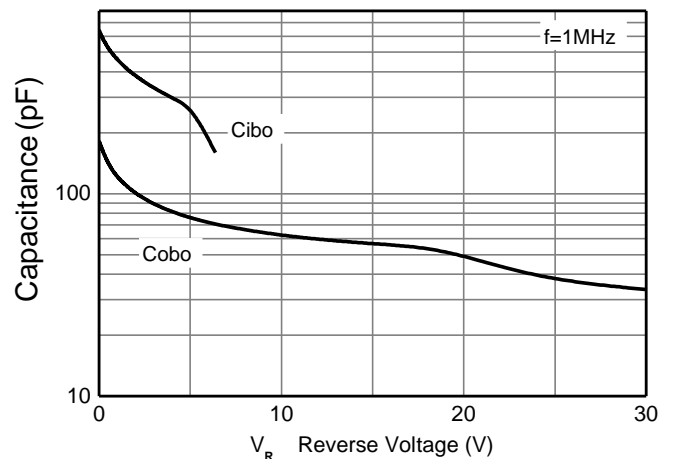
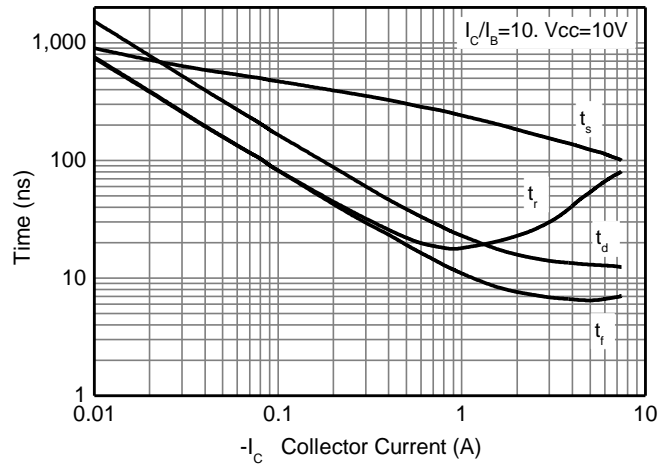
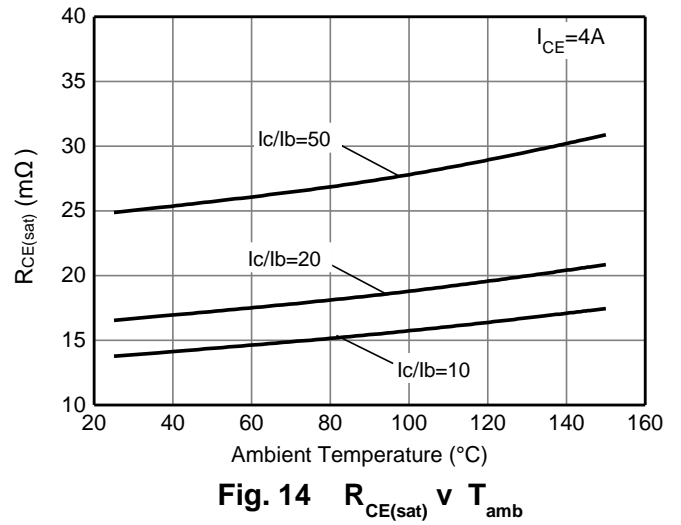
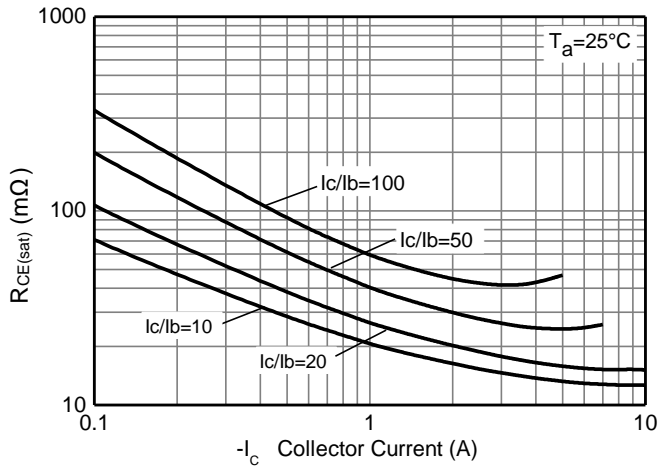


Fig. 12 Typical Junction Capacitance

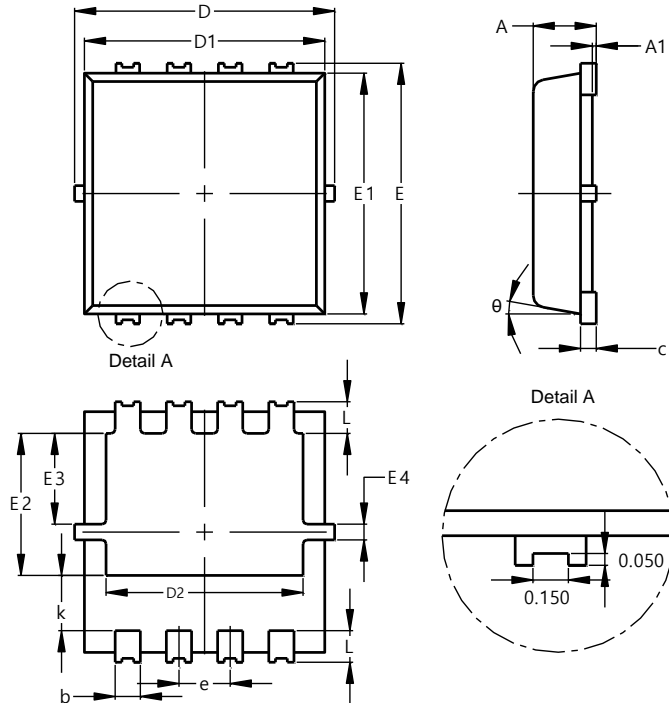
Typical Electrical Characteristics (continued) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

PowerDI3333-8/SWP (Type UX)

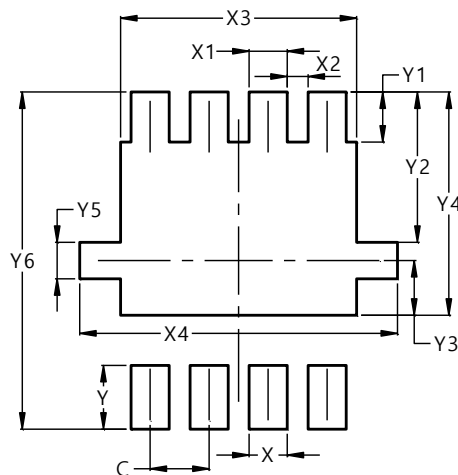


PowerDI3333-8/SWP (Type UX)			
Dim	Min	Max	Typ
A	0.75	0.85	0.80
A1	0.00	0.05	--
b	0.25	0.40	0.32
c	0.10	0.25	0.15
D	3.20	3.40	3.30
D1	2.95	3.15	3.05
D2	2.30	2.70	2.50
E	3.20	3.40	3.30
E1	2.95	3.15	3.05
E2	1.60	2.00	1.80
E3	0.95	1.35	1.15
E4	0.10	0.30	0.20
e	--	--	0.65
k	0.50	0.90	0.70
L	0.30	0.50	0.40
theta	0°	12°	10°
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

PowerDI3333-8/SWP (Type UX)



Dimensions	Value (in mm)
C	0.650
X	0.420
X1	0.420
X2	0.230
X3	2.600
X4	3.500
Y	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700

Note: 11. Side wall tin plated package for wettable flanks in AOI.

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